MMBT5401

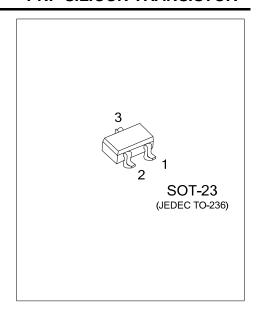
PNP SILICON TRANSISTOR

HIGH VOLTAGE SWITCHING TRANSISTOR

■ FEATURES

*Collector-Emitter Voltage: V_{CEO}=-150V

*High Current Gain



■ ORDERING INFORMATION

Oudoring Niverbox	Package	Pin Assignment			Dooking	
Ordering Number		1	2	3	Packing	
MMBT5401G-x-AE3-R	SOT-23	E	В	С	Tape Reel	

Note: Pin Assignment: E: Emitter B: Base C: Collector

MMBT5401G-x-AE3-R

(1)Packing Type
(2)Package Type
(3)Rank
(4)Green Package
(1) R: Tape Reel
(2) AE3: SOT-23
(3) x: refer to Classification of h_{FE}
(4) G: Halogen Free and Lead Free

■ MARKING



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■ ABSOLUATE MAXIUM RATINGS (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector -Base Voltage	V_{CBO}	-160	V
Collector -Emitter Voltage	V_{CEO}	-150	V
Emitter -Base Voltage	V_{EBO}	-5	V
DC Collector Current	Ic	-600	mA
Power Dissipation	P _D	350	mW
Junction Temperature	TJ	+150	ů
Storage Temperature	T _{STG}	-55 ~ + 150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Collector-Base Breakdown Voltage	BV _{CBO}	I _C =-100μA, I _E =0	-160			V	
Collector-Emitter Breakdown Voltage	BV _{CEO}	$I_C=-1$ mA, $I_B=0$	-150			V	
Emitter-Base Breakdown Voltage	BV_{EBO}	I _E =-10μA, I _C =0	-5			V	
Collector Cut-off Current	I _{CBO}	V _{CB} =-120V, I _E =0			-50	nA	
Emitter Cut-off Current	I _{EBO}	V_{BE} =-3V, I_{C} =0			-50	nA	
DC Current Gain(Note)	h _{FE}	V_{CE} =-5V, I_{C} =-1mA	80				
		V_{CE} =-5V, I_{C} =-10mA	80	160	400		
		V _{CE} =-5V, I _C =-50mA	80				
Collector-Emitter Saturation Voltage	VOE(0.4T)	I _C =-10mA, I _B =-1mA			-0.2	- V - V	
		I_C =-50mA, I_B =-5mA			-0.5		
Base-Emitter Saturation Voltage	VRE(QAT)	I _C =-10mA, I _B =-1mA			-1		
		I_C =-50mA, I_B =-5mA			-1		
Current Gain Bandwidth Product	f _T	V _{CE} =-10V, I _C =-10mA, f=100MHz	100		300	MHz	
Output Capacitance	Сов	V _{CB} =-10V, I _E =0, f=1MHz			6.0	pF	
Noise Figure	NF	I_{C} =-0.25mA, V_{CE} =-5V R _S =1k Ω , f=10Hz ~ 15.7kHz			8	dB	

Note: Pulse test: P_W <300 μ s, Duty Cycle<2%

■ CLASSIFICATION OF h_{FE}

RANK	А	В	С
RANGE	80-170	150-240	200-400

■ TYPICAL CHARACTERICS

Fig.1 Collector Output Capacitance

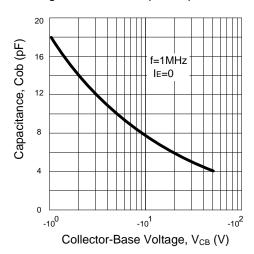


Fig.3 Base-Emitter on Voltage

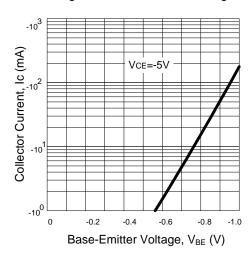


Fig.5 Current Gain-Bandwidth Product

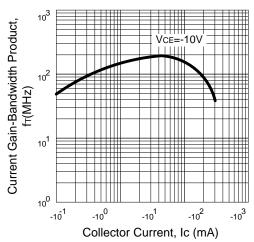


Fig.2 DC Current Gain

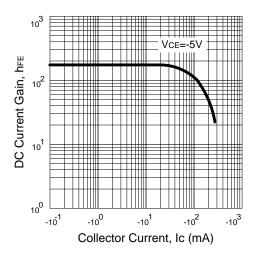
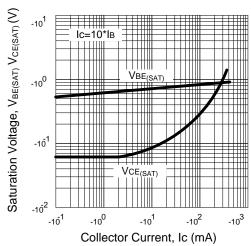


Fig.4 Saturation Voltage



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